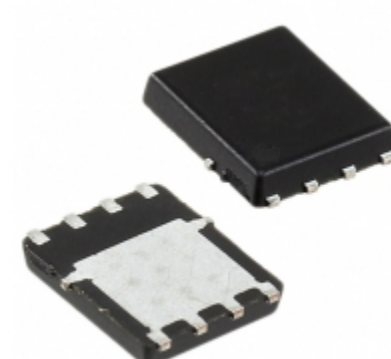


SI7772DP-T1-GE3	
Numero di parte	SI7772DP-T1-GE3
fabbricante	Vishay / Siliconix
Descrizione	MOSFET N-CH 30V 35.6A PPAK SO-8
quantità disponibile	17565 pcs in stock
Schede tecniche	
SI7772DP-T1-GE3 Price	Richiedi prezzo e tempi di consegna online or Email us: Info@ariat-tech.com


[RICIEDI UN PREVENTIVO](#)
Informazioni tecniche di SI7772DP-T1-GE3

codice articolo del costruttore	SI7772DP-T1-GE3	Categoria	Prodotti a semiconduttore discreti
fabbricante	Vishay / Siliconix	Descrizione	MOSFET N-CH 30V 35.6A PPAK SO-8
Pacchetto / caso	Tape & Reel (TR)	quantità disponibile	17565
Serie	SkyFET®, TrenchFET®	Tecnologia	MOSFET (Metal Oxide)
temperatura di esercizio	-55°C ~ 150°C (TJ)	Tipo montaggio	Surface Mount
Contenitore / involucro	PowerPAK® SO-8	Contenitore dispositivo fornitore	PowerPAK® SO-8
Dissipazione di potenza (max)	3.9W (Ta), 29.8W (Tc)	Tipo FET	N-Channel
Caratteristica FET	-	Tensione drain-source (Vdss)	30V
Corrente - Drain continuo (Id) @ 25 ° C	35.6A (Tc)	Rds On (max) a Id, Vgs	13 mOhm @ 15A, 10V
Vgs (th) (max) a Id	2.5V @ 250µA	Carica Gate (Qg) (Max) @ Vgs	28nC @ 10V
Capacità di ingresso (Ciss) (Max) @ Vds	1084pF @ 15V	imballaggio	Tape & Reel (TR)

SI7772DP-T1-GE3 17565 pezzi Nuovo e originale in magazzino, trova SI7772DP-T1-GE3 Stock, scheda tecnica, PDF, inventario presso Ariat-Tech .com online, ordina SI7772DP-T1-GE3 Vishay / Siliconix con garanzia e garanzia. RFQ SI7772DP-T1-GE3: Info@Ariat-Tech.com

Parti correlate per SI7772DP-T1-GE3

Immagine	Numero di parte	Descrizione	fabbricante	Quantità
	SI7792DP-T1-GE3	MOSFET N-CH 30V P-PACK SO-8	Electro-Films (EFI) / Vishay	1000 pcs
	SI7742DP-T1-GE3	MOSFET N-CH 30V 60A PPAK SO-8	Vishay / Siliconix	1000 pcs
	SI7758DP-T1-GE3	MOSFET N-CH 30V 60A PPAK SO-8	Electro-Films (EFI) / Vishay	5940 pcs
	SI7748DP-T1-GE3	MOSFET N-CH 30V 50A PPAK SO-8	Vishay / Siliconix	45000 pcs
	SI7790DP-T1-E3	SI7790DP-T1-E3 VISHAY	Vishay	500 pcs
	SI7788DP-T1-GE3	MOSFET N-CH 30V 50A PPAK SO-8	Vishay / Siliconix	2196 pcs
	SI7772DP-T1-GE3	MOSFET N-CH 30V 35.6A PPAK SO-8	Electro-Films (EFI) / Vishay	17565 pcs
	SI7758DP-T1-GE3	MOSFET N-CH 30V 60A PPAK SO-8	Vishay / Siliconix	5940 pcs
	SI7742DP	SI7742DP SI	SI	404 pcs
	SI7742DP-T1-GE3	MOSFET N-CH 30V 60A PPAK SO-8	Electro-Films (EFI) / Vishay	1000 pcs
	SI7742DP-T1-E3	SI7742DP-T1-E3 VISHAY	Vishay	1404 pcs
	SI7758DP	SI7758DP VB	VB	1000 pcs
	SI7774DP-T1-GE3	MOSFET N-CH 30V 60A PPAK SO-8	Electro-Films (EFI) / Vishay	1000 pcs
	SI7790DP-T1-GE3	MOSFET N-CH 40V 50A PPAK SO-8	Electro-Films (EFI) / Vishay	798200 pcs
	SI7788DP-T1-GE3	MOSFET N-CH 30V 50A PPAK SO-8	Electro-Films (EFI) / Vishay	2196 pcs
	SI7784DP-T1-GE3	MOSFET N-CH 30V 35A PPAK SO-8	Electro-Films (EFI) / Vishay	3000 pcs
	SI7748DP-T1-GE3	MOSFET N-CH 30V 50A PPAK SO-8	Electro-Films (EFI) / Vishay	45000 pcs
	SI7774DP-T1-GE3	MOSFET N-CH 30V 60A PPAK SO-8	Vishay / Siliconix	1000 pcs
	SI7784DP-T1-GE3	MOSFET N-CH 30V 35A PPAK SO-8	Vishay / Siliconix	3000 pcs
	SI7790DP-T1-GE3	MOSFET N-CH 40V 50A PPAK SO-8	Vishay / Siliconix	798200 pcs

Chip IC e modulo IGBT - Codice articolo hot spare

SI7716ADN-T1-GE3	SI7716ADN-T1-GE3	SI7716DN-T1-GE3	SI7720DN-T1-E3	SI7720DN-T1-GE3
SI7720DN-T1-GE3	SI7726DN	SI7726DN-T1-E3	SI7726DN-T1-GE3	SI7726DN-T1-GE3
SI7732DP-T1-GE3	SI7738DP	SI7738DP-T1-3	SI7738DP-T1-E3	SI7738DP-T1-E3
SI7738DP-T1-GE3	SI7738DP-T1-GE3	SI7742DP-T1-E3	SI7742DP-T1-GE3	SI7742DP-T1-GE3
SI7748DP-T1-GE3	SI7748DP-T1-GE3	SI7758DP	SI7758DP-T1-GE3	SI7758DP-T1-GE3
SI7772DP-T1-GE3	SI7774DP-T1-GE3	SI7774DP-T1-GE3	SI7784DP-T1-GE3	SI7784DP-T1-GE3
SI7788DP-T1-GE3	SI7788DP-T1-GE3	SI7790DP-T1-E3	SI7790DP-T1-GE3	SI7790DP-T1-GE3
SI7792DP-T1-GE3	SI7794DP-T1-GE3	SI7798DP-T1-GE3	SI7804DN	SI7804DN-T1-E3
SI7804DN-T1-E3	SI7806ADN	SI7806ADN-T1-E3	SI7806ADN-T1-E3	SI7806ADN-T1-E3-PBF
SI7806ADN-T1-GE3	SI7806ADN-T1-GE3	SI7806AEDN-T1-E3	SI7806BDN	SI7806BDN-T1-GE3

Distributore componenti elettronici - Chip IC & Fornitore di moduli IGBT.

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